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## **T2035H Series**

## Snubberless<sup>™</sup> high temperature 20 A Triacs

## Main features

| Symbol                             | Value | Unit |
|------------------------------------|-------|------|
| I <sub>T(RMS)</sub>                | 20    | A    |
| V <sub>DRM</sub> /V <sub>RRM</sub> | 600   | V    |
| I <sub>GT (Q1)</sub>               | 35    | mA   |
| T <sub>j MAX</sub>                 | 150   | °C   |

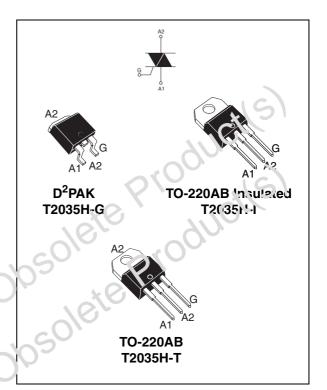
### Description

Specifically designed to operate at 150° C, the new 20 A T2035H Triacs provide an enhanced performance in terms of power loss and thermal dissipation. This facilitates the optimization of heatsink dimensioning, leading to improved space and cost effectiveness when compared to electromechanical solutions.

Based on ST Snubberless™ technology, the T2035H series offers high commutation ewitching capabilities and high noise immunity levels on the full range of T<sub>j</sub>.

The T2035H series factifiates the optimization of the control of universal motors and inductive loads found in oppliances such as vacuum cleaners and washing machines

The T.2005H Triacs are also suitable for use in high temperature er vilonment found in hot appliances such as cookers, ovens, hobs, electric heaters, and contra machines.



### Order code

| Part number    | Marking     |
|----------------|-------------|
| T2035H-600G    | T2035H-600G |
| T2035H-600G-TR | T2035H-600G |
| T2035H-600TRG  | T2035H-600T |
| T2035H-600IRG  | T2035H-600I |

TM: Snubberless is a trademark of STMicroelectronics

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## 1 Characteristics

| Table 1. | Absolute maximum ratings |           |
|----------|--------------------------|-----------|
| Symbol   |                          | Parameter |

| Symbol                             | Parameter  |                                |                         | Value                      | Unit |
|------------------------------------|--|--------------------------------|-------------------------|----------------------------|------|
| I <sub>T(RMS)</sub>                | RMS on-state current (full sine wave)                                      | D <sup>2</sup> PAK<br>TO-220AB | T <sub>c</sub> = 127° C | 20                         | A    |
|                                    |  | TO-220AB Ins                   | T <sub>c</sub> = 105° C |                            |      |
|                                    | Non repetitive surge peak on-state current                                 | F = 60 Hz                      | t = 16.7 ms             | 210                        | А    |
| ITSM                               | (full cycle sine wave, $T_j$ initial = 25° C)                              | F = 50 Hz                      | t = 20 ms               | 200                        | ~    |
| l²t                                | I <sup>2</sup> t Value for fusing  | tp = 1                         | 0 ms                    | 283 C                      | .∿²s |
| dl/dt                              | Critical rate of rise of on-state current $I_G = 2xI_{GT}$ , tr ≤100 ns    | F = 120 Hz                     | T <sub>j</sub> = 125° C | 50                         | A/µs |
| V <sub>DSM</sub> /V <sub>RSM</sub> | Non repetitive surge peak off state voltage                                | •                              | T <sub>j</sub> = 25° C  | 700                        | V    |
| I <sub>GM</sub>                    | Peak gate current  | t <sub>p</sub> = 20 μs         | $T_j = 750^{\circ} C$   | 4                          | А    |
| P <sub>G(AV)</sub>                 | Average gate power dissipation   | ×                              | T <sub>j</sub> = 150° C | OL/                        | W    |
| T <sub>stg</sub><br>T <sub>j</sub> | Storage junction temperature range<br>Operating junction temperature range | coler                          | 0100                    | -40 to +150<br>-30 to +150 | °C   |
| Τ <sub>Ι</sub>                     | Maximum leads soldering temperature during                                 | (1)5                           | N'                      | 260                        | °C   |

### Table 2. Electrical characteristics (T<sub>i</sub> = 25° C, unless otherwise specified)

| Symbol                         | Test cor diaons  | Quadrant |       | Value | Unit |
|--------------------------------|--|----------|-------|-------|------|
| I <sub>GT</sub> <sup>(1)</sup> | $V_{\rm D} = 12 \text{ V}, \text{ R}_{\rm I} = 33 \Omega$                  | -    -   | MAX   | 35    | mA   |
| V <sub>GT</sub>                | $v_{\rm D} = 12 v, n_{\rm L} = 352$  | -    -   | MAX   | 1.3   | V    |
| V <sub>GD</sub>                | $V_D = v_{j,jE,M}, P_L = 3.3 \text{ k}\Omega, T_j = 150^{\circ} \text{ C}$ | -    -   | MIN   | 0.15  | V    |
| I <sub>H</sub> <sup>(2)</sup>  | l- = 100 mA  |          | MAX   | 35    | mA   |
|                                | I <sub>G</sub> = 1.2 x I <sub>GT</sub>                                     | -        | МАХ   | 50    | mA   |
| CO C                           | $r_{G} = 1.2 \times r_{GT}$  | Ш        | IVIAA | 80    |      |
| u v/dt <sup>(2)</sup>          | $V_D = 67\% V_{DRM}$ , gate open, $T_j = 150^{\circ} C$                    |          | MIN   | 300   | V/µs |
| (dl/dt)c <sup>(2)</sup>        | Without snubber, T <sub>j</sub> = 150° C                                   |          | MIN   | 8.9   | A/ms |

1. minimum  $I_{GT}$  is guaranteed at 5% of  $I_{GT}$  max

2. for both polarities of A2 referenced to A1

| Symbol                               | Test condition                                  | ons         |     | Value | Unit |
|--------------------------------------|---|-------------|-----|-------|------|
| V <sub>TM</sub> <sup>(1)</sup>       | I <sub>TM</sub> = 28 A, t <sub>p</sub> = 380 μs | Tj = 25° C  | MAX | 1.5   | V    |
| V <sub>TO</sub> <sup>(1)</sup>       |   | Tj = 150° C | MAX | 0.80  | V    |
| R <sub>D</sub> <sup>(1)</sup>        |   | Tj = 150° C | MAX | 21    | mΩ   |
|                                      | <u> </u>  | Tj = 25° C  |     | 5     | μA   |
| I <sub>DRM</sub><br>I <sub>RRM</sub> | V <sub>DRM</sub> = V <sub>RRM</sub>             | Tj = 150° C | MAX | 7.4   | m۸   |
| 'RRM                                 | $V_D/V_R = 400 V$ (at peak mains voltage)       | Tj = 150° C |     | 4.8   | mA   |

#### Table 3. Static electrical characteristics

1. for both polarities of A2 referenced to A1

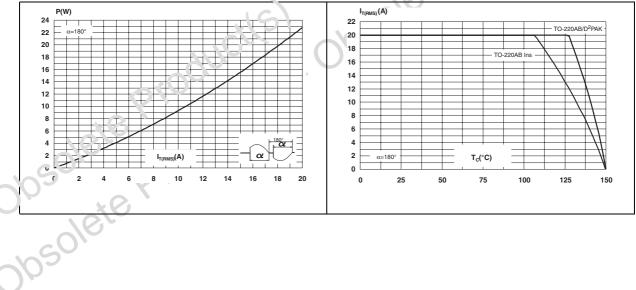
#### Table 4. **Thermal resistance**

| Symbol                | Para                           | ameter               |                                | Va ue | Unit |
|-----------------------|--------------------------------|----------------------|--------------------------------|-------|------|
| R <sub>th (j-c)</sub> | Junction to case for full (AC) |                      | D <sup>2</sup> PAK<br>TO-220AB | 1     |      |
|                       |                                |                      | TO-220AB In                    | 1.9   | S    |
|                       |                                | $S = 1 \text{ cm}^2$ | D <sup>2</sup> PA.             | 45    | °C/W |
| R <sub>th (j-a)</sub> | Junction to ambient            | G                    | 10.220AB Ins                   | 60    |      |

#### Maximum power dissipation vs Figure 1. RMS on-state current (full cycle)

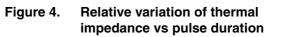
F gure 2.

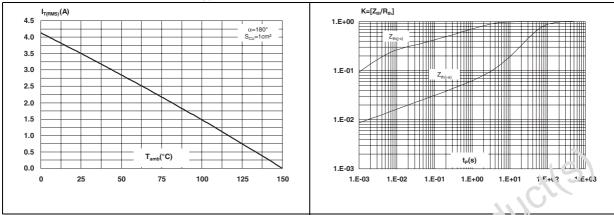
### RMS on-state current versus case temperature





### Figure 3. RMS on-state current vs ambient temperature (epoxy printed circuit board FR4 e<sub>cu</sub> = 35 μm)





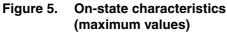


Figure 6. Surge peak on-state current vs number of cycles

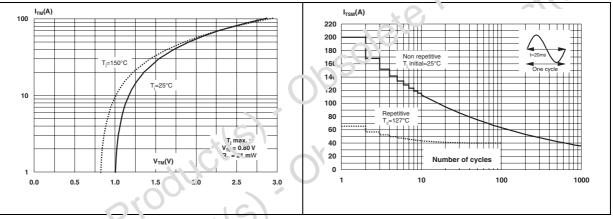
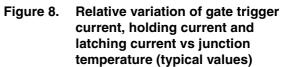
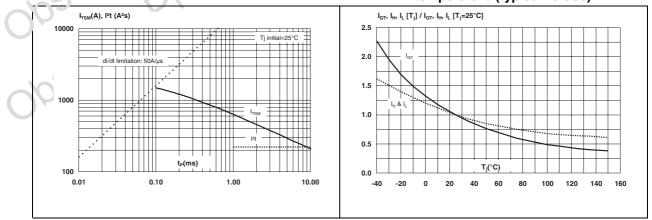
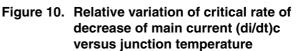


Figure 7. Non repetitive surge peak on-state





# Figure 9. Relative variation of critical rate of decrease of main current (di/dt)c vs reapplied (dV/dt)c



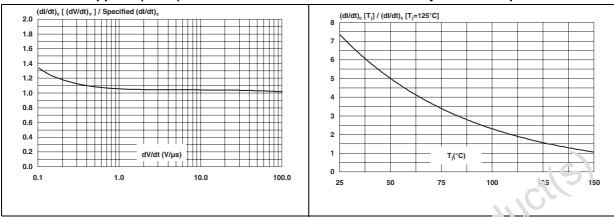
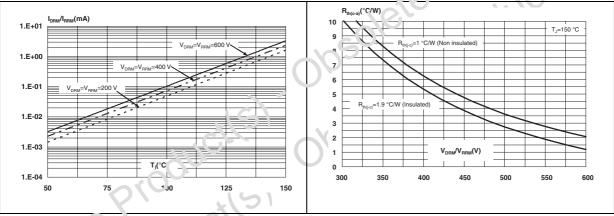
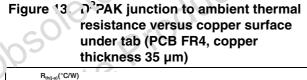
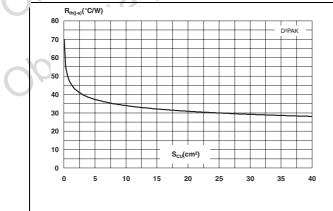


Figure 11. Leakage current versus junction temperature for different values of blocking voltage (typical values)

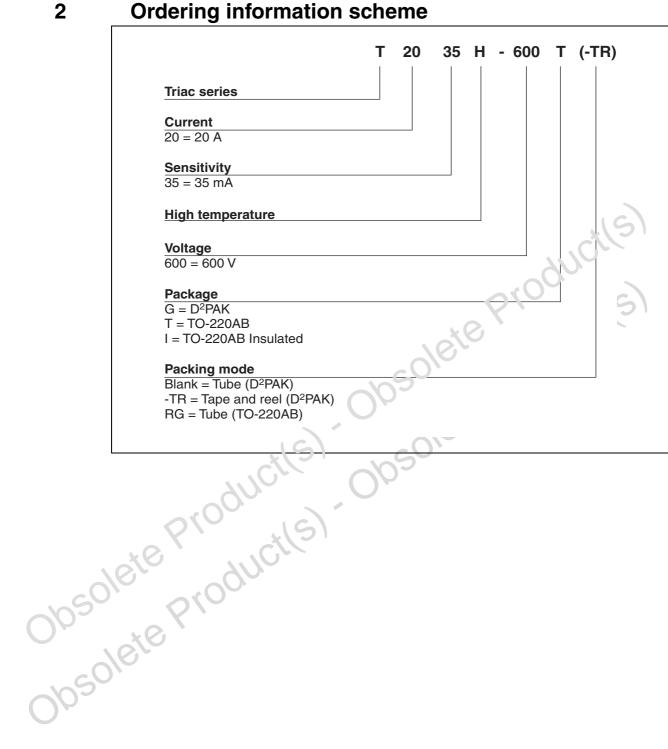
Figure 12. Acceptable repelitive peak off-state voltage versus case-ambient thermel resistance















## **3** Package information

|  |      |       |          | DIMEN | ISIONS        | ;      |       |
|--|------|-------|----------|-------|---------------|--------|-------|
|  | REF. | Mi    | illimete | rs    |               | Inches | i     |
|  |      | Min.  | Тур.     | Max.  | Min.          | Тур.   | Max.  |
|  | А    | 15.20 |          | 15.90 | 0.598         |        | 0.625 |
| в                                      | a1   |       | 3.75     |       |               | 0.147  |       |
|  | a2   | 13.00 |          | 14.00 | 0.511         | 10     | L 551 |
|  | В    | 10.00 |          | 10.40 | 0.393         |        | 0.409 |
|  | b1   | 0.61  |          | 0.88  | C 02`4        |        | 0.034 |
|  | b2   | 1.23  |          | 1.32  | <i>ن</i> .048 |        | 0.051 |
|  | С    | 4.40  |          | 1.60  | 0.173         |        | 0.181 |
|  | c1   | 0.49  |          | 0.70  | 0.019         |        | 0.027 |
| 12 a2                                  | c2   | 2.10  |          | 2.72  | 0.094         |        | 0.107 |
|  |      | 2.40  | 0        | 2.70  | 0.094         |        | 0.106 |
|  | F    | 6.20  | X        | 6.60  | 0.244         |        | 0.259 |
| e                                      | ØI   | 3.75  | C        | 3.85  | 0.147         |        | 0.151 |
| 16                                     | 14   | 15.80 | 16.40    | 16.80 | 0.622         | 0.646  | 0.661 |
|  | 2    | 2.65  |          | 2.95  | 0.104         |        | 0.116 |
| <i>200</i> 04                          | 12   | 1.14  |          | 1.70  | 0.044         |        | 0.066 |
| ~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~ | 13   | 1.14  |          | 1.70  | 0.044         |        | 0.066 |
| P1 (5)                                 | М    |       | 2.60     |       |               | 0.102  |       |
| obsolete Production                    |      |       |          |       |               |        |       |

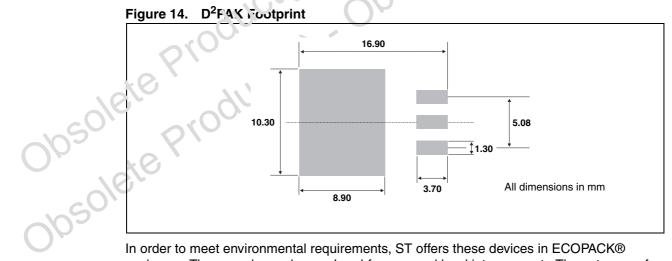
Table 5. TO-220AB and TO-220AB Insulated dimensions



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|    |                       |      |        | DIMEN  | SIONS |        |
|----|-----------------------|------|--------|--------|-------|--------|
|    |                       | REF. | Millim | neters | Inc   | hes    |
|    |                       |      | Min.   | Max.   | Min.  | Max.   |
|    |                       | Α    | 4.40   | 4.60   | 0.173 | 0.181  |
|    | <b>▲</b>              | A1   | 2.49   | 2.69   | 0.098 | 0.106  |
| E  | C2→                   | A2   | 0.03   | 0.23   | 0.001 | 0.009  |
|    |                       | В    | 0.70   | 0.93   | 0.027 | 0.037  |
|    | D                     | B2   | 1.14   | 1.70   | 0.045 | C.967  |
|    |                       | С    | 0.45   | 0.60   | 0.017 | 0.024  |
|    | <u>A1</u>             | C2   | 1.23   | 1.36   | 1.043 | 0.054  |
| B2 | / <u>c</u> , <u>r</u> | D    | 8.95   | 9.35   | 0.352 | 0.368  |
|    |                       | E    | 10.00  | 16.40  | 0.393 | 0.409  |
| ŭ  |                       | G    | 1 88   | 5.28   | 0.192 | 0.208  |
|    | 2mm min.<br>FLAT ZONE |      | າວ.00  | 15.85  | 0.590 | 0.624  |
|    |                       |      | 1.27   | 1.40   | 0.050 | 0.055  |
|    | V2                    | L3   | 1.40   | 1.75   | 0.055 | 0.069  |
|    | OF                    | М    | 2.40   | 3.20   | 0.094 | 0.126  |
|    |                       | R    | 0.40   | typ.   | 0.01  | 6 typ. |
|    | *(5)                  | V2   | 0°     | 8°     | 0°    | 8°     |

Table 6.D<sup>2</sup>PAK dimensions



In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a Lead-free second level interconnect. The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com.

#### **Ordering information** 4

| Part number    | Marking     | Package            | Weight | Base Qty | Packing mode  |
|----------------|-------------|--------------------|--------|----------|---------------|
| T2035H-600G    | T2035H-600G | D <sup>2</sup> PAK | 1.5 g  | 50       | Tube          |
| T2035H-600G-TR | T2035H-600G | D <sup>2</sup> PAK | 1.5 g  | 1000     | Tape and Reel |
| T2035H-600TRG  | T2035H-600T | TO-220AB           | 2.3 g  | 50       | Tube          |
| T2035H-600IRG  | T2035H-600I | TO-220ABIns        | 2.3 g  | 50       | Tube          |

#### 5 **Revision history**

| Date        | Revision | Charges                           |
|-------------|----------|-----------------------------------|
| 13-Jul-2006 | 1        | Initial release.                  |
| 7-Sep-2006  | 2        | Added TO-220AB Insulated package. |
|             | ucil     | 01050                             |
| ate Prof    |          | 61 01050                          |

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